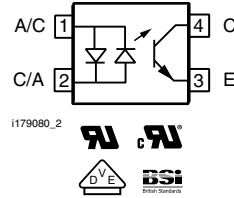
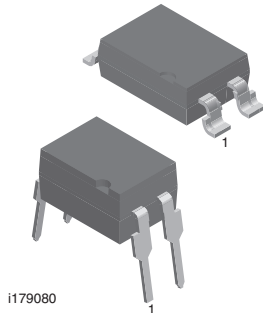


## Optocoupler, Phototransistor Output, AC Input



### FEATURES

- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V<sub>RMS</sub>
- High collector emitter voltage, V<sub>CEO</sub> = 70 V
- Low saturation voltage
- Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End-stackable, 0.100" (2.54 mm) spacing
- High common-mode interference immunity
- Compliant to RoHS Directive to 2002/95/EC and in accordance WEEE 2002/96/EC


**RoHS**  
COMPLIANT

### DESCRIPTION

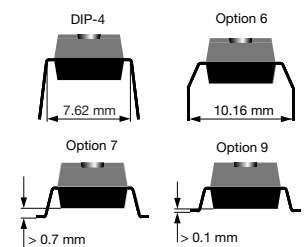
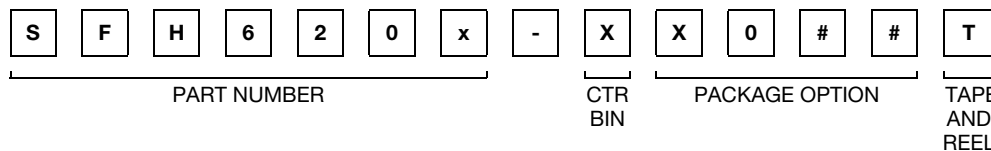
The SFH620A (DIP) and SFH6206 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits. The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm are achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation to an operation voltage of 400 V<sub>RMS</sub> or DC.

### AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-2 (VDE 0884)
- DIN EN 60747-5-5 (pending)

### ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)					
	± 10 mA					
	SFH620A			SFH6206		
	40 to 125	63 to 200	100 to 320	40 to 125	63 to 200	100 to 320
UL, cUL, BSI	40 to 125	63 to 200	100 to 320	40 to 125	63 to 200	100 to 320
DIP-4	SFH620A-1	SFH620A-2	SFH620A-3	-	-	-
DIP-4, 400 mil, option 6	SFH620A-1X006	SFH620A-2X006	SFH620A-3X006	-	-	-
SMD-4, option 7	-	SFH620A-2X007T <sup>(1)</sup>	-	-	-	-
SMD-4, option 9	-	-	-	SFH6206-1T <sup>(1)</sup>	SFH6206-2T <sup>(1)</sup>	SFH6206-3T <sup>(1)</sup>
VDE, UL, cUL, BSI	40 to 125	63 to 200	100 to 320	40 to 125	63 to 200	100 to 320
DIP-4	SFH620A-1X001	SFH620A-2X001	SFH620A-3X001	-	-	-
DIP-4, 400 mil, option 6	-	SFH620A-2X016	SFH620A-3X016	-	-	-
SMD-4, option 7	-	SFH620A-2X017T	-	-	-	-
SMD-4, option 9	-	-	-	-	SFH6206-2X001T <sup>(1)</sup>	SFH6206-3X001T <sup>(1)</sup>

### Note

<sup>(1)</sup> Also available in tubes, do not put T on the end.

<b>ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup></b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
DC forward current		$I_F$	$\pm 60$	mA
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	$I_{FSM}$	$\pm 2.5$	A
Power dissipation		$P_{diss}$	100	mW
<b>OUTPUT</b>				
Collector emitter voltage		$V_{CE}$	70	V
Emitter collector voltage		$V_{EC}$	7	V
Collector current		$I_C$	50	mA
	$t_p \leq 1\text{ }\mu\text{s}$	$I_C$	100	mA
Power dissipation		$P_{diss}$	150	mW
<b>COUPLER</b>				
Isolation test voltage between emitter and detector	$t = 1\text{ s}$	$V_{ISO}$	5300	$V_{RMS}$
Isolation voltage		$V_{IORM}$	890	$V_P$
Total power dissipation		$P_{tot}$	250	mW
Creepage distance			$\geq 7$	mm
Clearance distance			$\geq 7$	mm
Insulation thickness between emitter and detector			$\geq 4$	mm
Comparative tracking index per DIN IEC112/ VDE 0303, part 1		CTI	175	
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{11}$	$\Omega$
Storage temperature range		$T_{stg}$	- 55 to + 150	$^{\circ}\text{C}$
Ambient temperature range		$T_{amb}$	- 55 to + 100	$^{\circ}\text{C}$
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Soldering temperature <sup>(2)</sup>	max. 10 s, dip soldering distance	$T_{sld}$	260	$^{\circ}\text{C}$

**Notes**

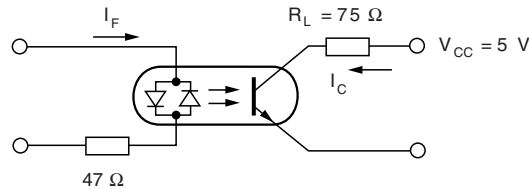
- (1) Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (2) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

<b>ELECTRICAL CHARACTERISTICS <sup>(1)</sup></b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>							
Forward voltage	$I_F = \pm 60\text{ mA}$		$V_F$		1.25	1.65	V
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$		$C_O$		50		pF
Thermal resistance			$R_{thja}$		750		K/W
<b>OUTPUT</b>							
Collector emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$		$C_{CE}$		6.8		pF
Thermal resistance			$R_{thja}$		500		$^{\circ}\text{C/W}$
<b>COUPLER</b>							
Collector emitter saturation voltage	$I_F = 10\text{ mA}, I_C = 2.5\text{ mA}$		$V_{CEsat}$		0.25	0.4	V
Coupling capacitance			$C_C$		0.2		pF
Collector emitter leakage current	$V_{CE} = 10\text{ V}$	SFH620A-1	$I_{CEO}$		2	50	nA
		SFH6206-1	$I_{CEO}$		2	50	nA
		SFH620A-2	$I_{CEO}$		2	50	nA
		SFH6206-2	$I_{CEO}$		2	50	nA
		SFH620A-3	$I_{CEO}$		5	100	nA
		SFH6206-3	$I_{CEO}$		5	100	nA

**Note**

- (1) Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.  
Still air, coupler soldered to PCB or base.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$V_{CE} = 5\text{ V}, I_F = \pm 10\text{ mA}$	SFH620A-1	CTR	40		125	%
		SFH6206-1	CTR	40		125	%
		SFH620A-2	CTR	63		200	%
		SFH6206-2	CTR	63		200	%
		SFH620A-3	CTR	100		320	%
		SFH6206-3	CTR	100		320	%
	$V_{CE} = 5\text{ V}, I_F = \pm 1\text{ mA}$	SFH620A-1	CTR	13	30		%
		SFH6206-1	CTR	13	30		%
		SFH620A-2	CTR	22	45		%
		SFH6206-2	CTR	22	45		%
		SFH620A-3	CTR	34	70		%
		SFH6206-3	CTR	34	70		%



isfh620a\_08

Fig. 1 - Switching Times Linear Operation (without Saturation)

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$R_L = 75\ \Omega, I_F = 10\text{ mA}, V_{CC} = 5\text{ V}$	$t_{on}$		3		$\mu\text{s}$
Rise time	$R_L = 75\ \Omega, I_F = 10\text{ mA}, V_{CC} = 5\text{ V}$	$t_r$		2		$\mu\text{s}$
Turn-off time	$R_L = 75\ \Omega, I_F = 10\text{ mA}, V_{CC} = 5\text{ V}$	$t_{off}$		2.3		$\mu\text{s}$
Fall time	$R_L = 75\ \Omega, I_F = 10\text{ mA}, V_{CC} = 5\text{ V}$	$t_f$		2		$\mu\text{s}$
Cut-off frequency	$R_L = 75\ \Omega, I_F = 10\text{ mA}, V_{CC} = 5\text{ V}$	$t_{ctr}$		250		kHz

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
$V_{IOTM}$			10 000			V
$V_{IORM}$			890			V
$P_{SO}$					400	mW
$I_{SI}$					275	mA
$T_{SI}$					175	$^{\circ}\text{C}$
Creepage distance	Standard DIP-4		7			mm
Clearance distance	Standard DIP-4		7			mm
Creepage distance	400 mil DIP-4		8			mm
Clearance distance	400 mil DIP-4		8			mm
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm

#### Note

- As per IEC 60747-5-5, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

## TYPICAL CHARACTERISTICS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

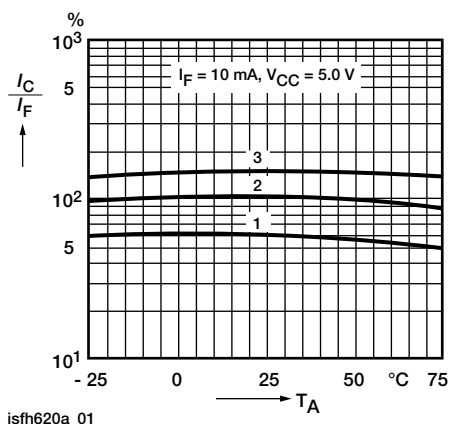


Fig. 2 - Current Transfer Ratio (CTR) vs. Temperature

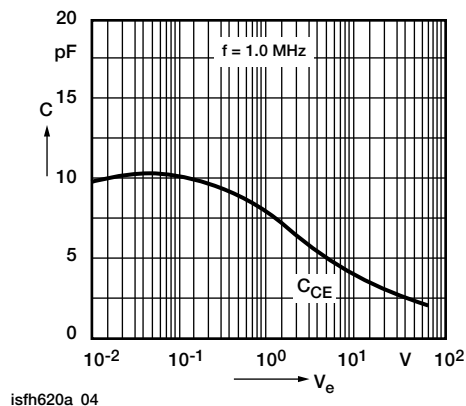


Fig. 5 - Transistor Capacitance (Typ.) vs. Collector Emitter Voltage

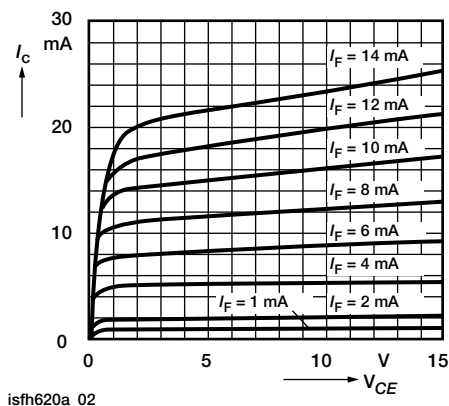


Fig. 3 - Output Characteristics (Typ.) Collector Current vs. Collector Emitter Voltage

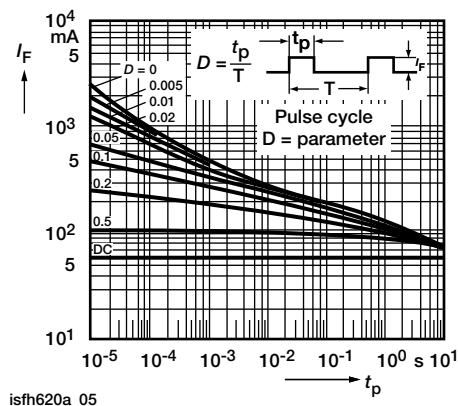


Fig. 6 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

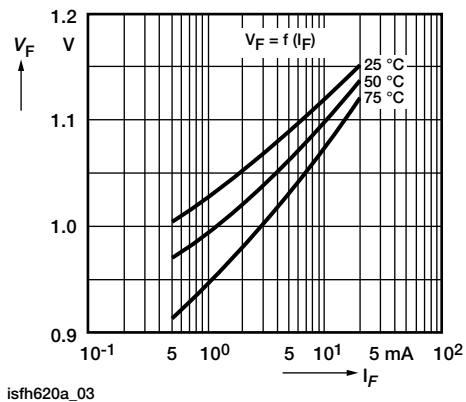


Fig. 4 - Diode Forward Voltage (Typ.) vs. Forward Current

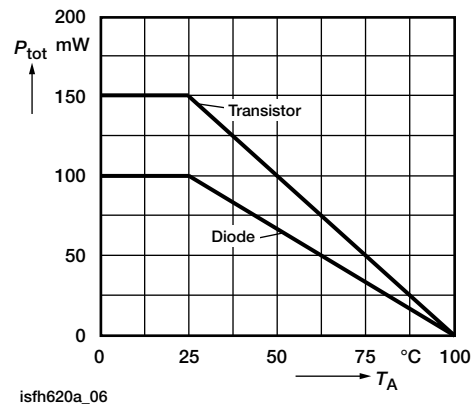


Fig. 7 - Permissible Power Dissipation vs. Ambient Temperature

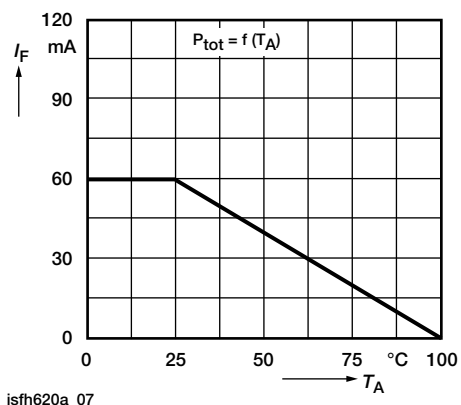
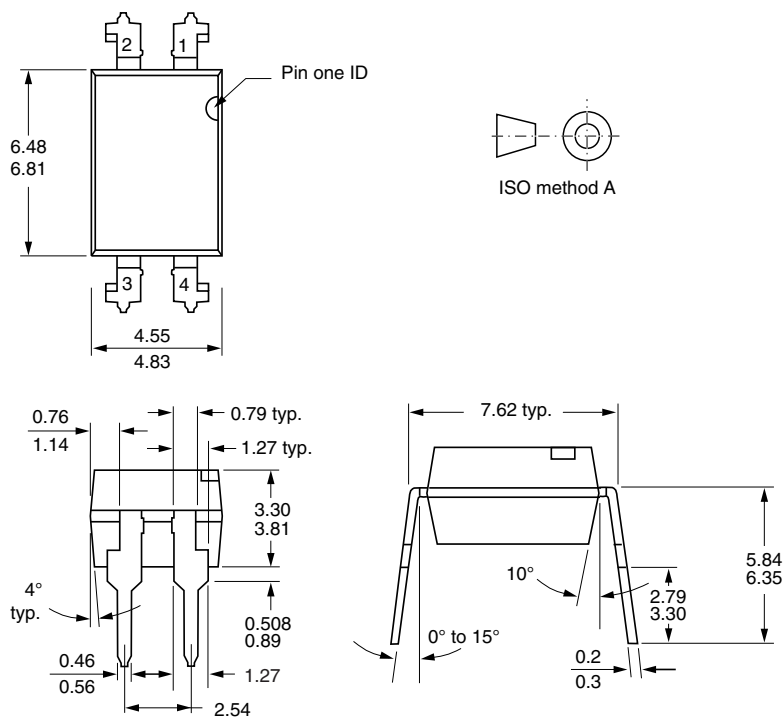


Fig. 8 - Permissible Diode Forward Current vs. Ambient Temperature

# **PACKAGE DIMENSIONS** in millimeters

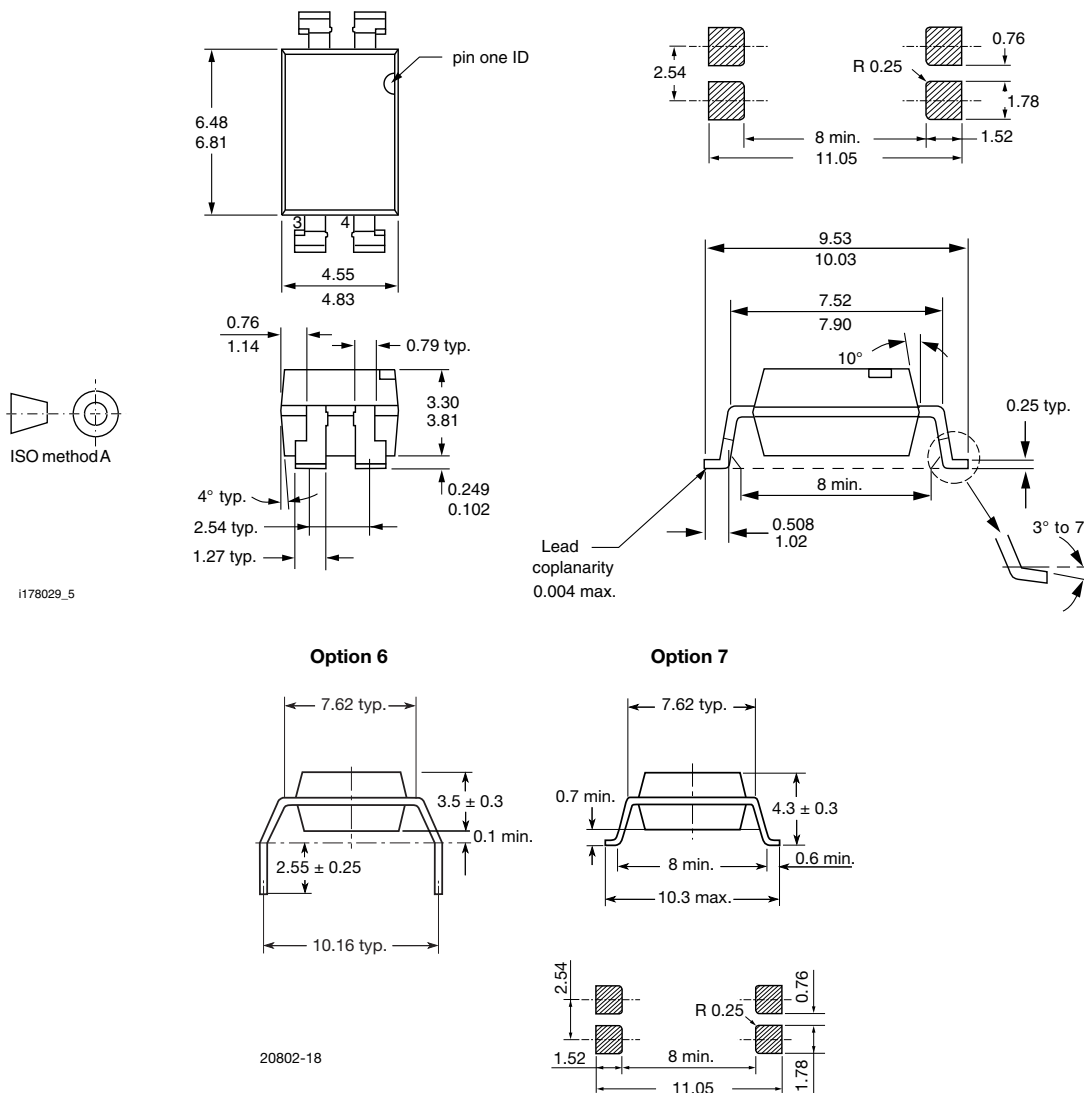


# SFH620A, SFH6206

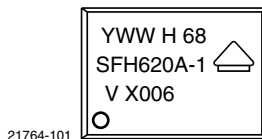
Vishay Semiconductors Optocoupler, Phototransistor Output,  
AC Input



## PACKAGE DIMENSIONS in millimeters



## PACKAGE MARKING (example)





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